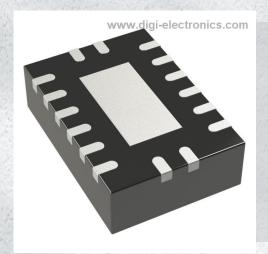


# 74HC165BQ,115 Datasheet



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DiGi Electronics Part Number 74HC165BQ,115-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number 74HC165BQ,115

Description IC 8BIT SHIFT REGISTER 16-DHVQFN

Detailed Description Shift Shift Register 1 Element 8 Bit 16-DHVQFN (2.5

x3.5)



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### **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
74HC165BQ,115	Nexperia USA Inc.
Series:	Product Status:
74HC	Active
Logic Type:	Output Type:
Shift Register	Complementary
Number of Elements:	Number of Bits per Element:
1	8
Function:	Voltage - Supply:
Parallel or Serial to Serial	2V ~ 6V
Operating Temperature:	Mounting Type:
-40°C ~ 125°C	Surface Mount
Package / Case:	Supplier Device Package:
16-VFQFN Exposed Pad	16-DHVQFN (2.5x3.5)
Base Product Number:	
74HC165	

### **Environmental & Export classification**

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

### 8-bit parallel-in/serial out shift register

Rev. 7 — 1 September 2021

**Product data sheet** 

#### 1. General description

The 74HC165; 74HCT165 are 8-bit serial or parallel-in/serial-out shift registers. The device features a serial data input (DS), eight parallel data inputs (D0 to D7) and two complementary serial outputs (Q7 and  $\overline{\text{Q7}}$ ). When the parallel load input ( $\overline{\text{PL}}$ ) is LOW the data from D0 to D7 is loaded into the shift register asynchronously. When  $\overline{\text{PL}}$  is HIGH data enters the register serially at DS. When the clock enable input ( $\overline{\text{CE}}$ ) is LOW data is shifted on the LOW-to-HIGH transitions of the CP input. A HIGH on  $\overline{\text{CE}}$  will disable the CP input. Inputs are overvoltage tolerant to 15 V. This enables the device to be used in HIGH-to-LOW level shifting applications.

#### 2. Features and benefits

- Wide supply voltage range from 2.0 to 6.0 V
- · CMOS low power dissipation
- · High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- · Asynchronous 8-bit parallel load
- · Synchronous serial input
- Input levels:
  - For 74HC165: CMOS level
  - For 74HCT165: TTL level
- Complies with JEDEC standards:
  - JESD8C (2.7 V to 3.6 V)
  - JESD7A (2.0 V to 6.0 V)
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

### 3. Applications

· Parallel-to-serial data conversion

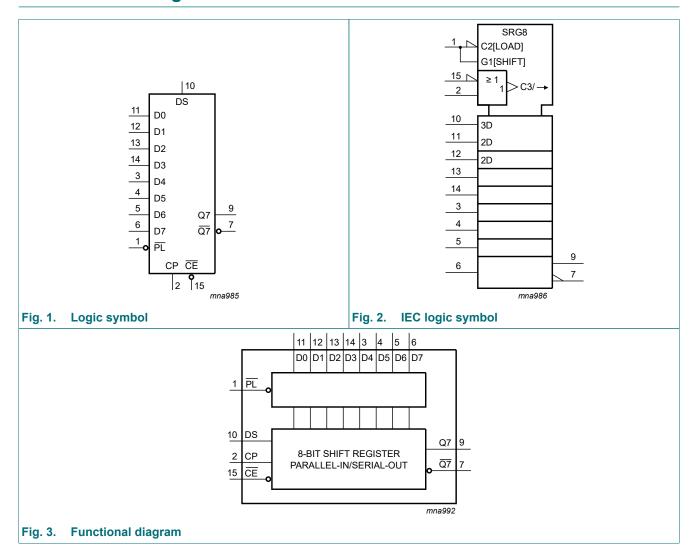


### 4. Ordering information

**Table 1. Ordering information** 

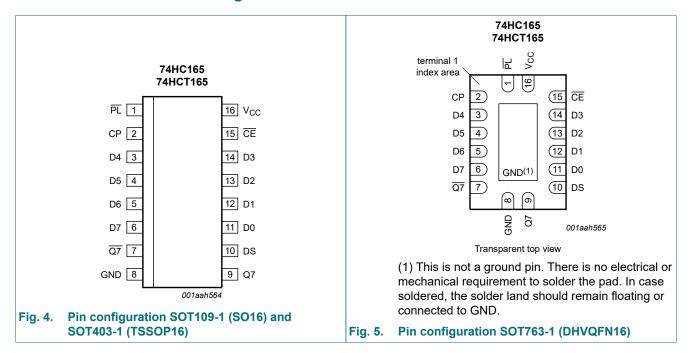
Type number	Package									
	Temperature range	Name	Description	Version						
74HC165D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1						
74HCT165D			body width 3.9 mm							
74HC165PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1						
74HCT165PW			body width 4.4 mm							
74HC165BQ	-40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1						
74HCT165BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm							

### 5. Functional diagram



### 6. Pinning information

#### 6.1. Pinning



#### 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
PL	1	asynchronous parallel load input (active LOW)
CP	2	clock input (LOW-to-HIGH edge-triggered)
Q7	7	complementary output from the last stage
GND	8	ground (0 V)
Q7	9	serial output from the last stage
DS	10	serial data input
D0 to D7	11, 12, 13, 14, 3, 4, 5, 6	parallel data inputs (also referred to as Dn)
CE	15	clock enable input (active LOW)
V <sub>CC</sub>	16	positive supply voltage

### 7. Functional description

#### Table 3. Function table

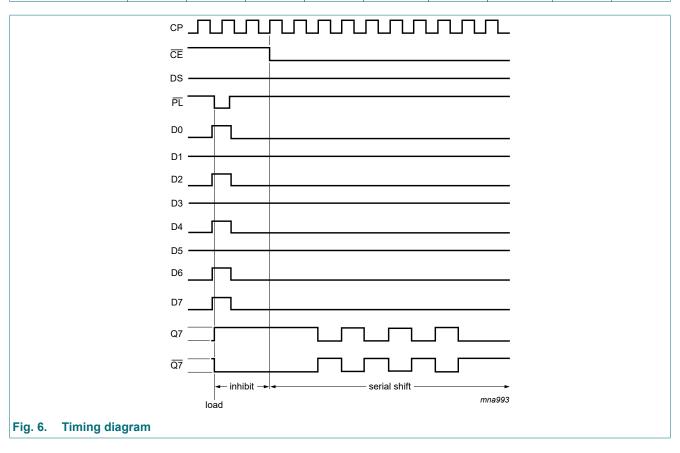
H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level; I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

q = state of the referenced output one set-up time prior to the LOW-to-HIGH clock transition;

 $X = don't care; \uparrow = LOW-to-HIGH clock transition.$ 

Operating modes	Inputs	Inputs					sters	Output	Outputs	
	PL	CE	СР	DS	D0 to D7	Q0	Q1 to Q6	Q7	Q7	
parallel load	L	Х	Х	Х	L	L	L to L	L	Н	
	L	Х	Х	Х	Н	Н	H to H	Н	L	
serial shift	Н	L	1	I	Х	L	q0 to q5	q6	q6	
	Н	L	1	h	Х	Н	q0 to q5	q6	<del>q6</del>	
	Н	1	L	I	Х	L	q0 to q5	q6	q6	
	Н	1	L	h	Х	Н	q0 to q5	q6	<del>q6</del>	
hold "do nothing"	Н	Н	Х	Х	Х	q0	q1 to q6	q7	<del>q7</del>	
	Н	Х	Н	Х	Х	q0	q1 to q6	q7	<del>q7</del>	



### 8. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
Io	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### 9. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC165			74HCT16	5	Unit
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

#### 10. Static characteristics

#### **Table 6. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C		-40 ° +85	C to	-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	5									
$V_{IH}$	V <sub>IH</sub> HIGH-level input	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level input	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
v	voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

<sup>[2]</sup> For SOT109-1 (SO16) package: P<sub>tot</sub> derates linearly with 12.4 mW/K above 110 °C.

For SOT403-1 (TSSOP16) package: Ptot derates linearly with 8.5 mW/K above 91 °C.

For SOT763-1 (DHVQFN16) package: Ptot derates linearly with 11.2 mW/K above 106 °C.

### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C		_	°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OH</sub>	HIGH-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O}$ = -5.2 mA; $V_{CC}$ = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
$V_{OL}$	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	٧
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	65									
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	8.0	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 V$								
	output voltage	Ι <sub>Ο</sub> = -20 μΑ	4.4	4.5	-	4.4	-	4.4	-	٧
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		Dn and DS inputs	-	35	126	-	157.5	-	171.5	μΑ
		CP, CE, and PL inputs	-	65	234	-	292.5	-	318.5	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF

### 11. Dynamic characteristics

#### **Table 7. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF unless otherwise specified; for test circuit, see Fig. 12

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC16	5									
t <sub>pd</sub>	propagation	CP or CE to Q7, Q7; see Fig. 7 [1]								
	delay	V <sub>CC</sub> = 2.0 V	-	52	165	-	205	-	250	ns
		V <sub>CC</sub> = 4.5 V	-	19	33	-	41	-	50	ns
		V <sub>CC</sub> = 6.0 V	-	15	28	-	35	-	43	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
		PL to Q7, Q7; see Fig. 8								
		V <sub>CC</sub> = 2.0 V	-	50	165	-	205	-	250	ns
		V <sub>CC</sub> = 4.5 V	-	18	33	-	41	-	50	ns
		V <sub>CC</sub> = 6.0 V	-	14	28	-	35	-	43	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		D7 to Q7, Q7; see Fig. 9								
		V <sub>CC</sub> = 2.0 V	-	36	120	-	150	-	180	ns
		V <sub>CC</sub> = 4.5 V	-	13	24	-	30	-	36	ns
		V <sub>CC</sub> = 6.0 V	-	10	20	-	26	-	31	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	11	-	-	-	-	-	ns
t <sub>t</sub>	transition time	Q7, Q7 output; see Fig. 7 [2]								
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns
$t_{W}$	pulse width	CP input HIGH or LOW; see Fig. 7								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		PL input LOW; see Fig. 8								
		V <sub>CC</sub> = 2.0 V	80	14	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	5	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	4	-	17	-	20	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Fig. 8								
		V <sub>CC</sub> = 2.0 V	100	22	-	125	-	150	-	ns
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
		V <sub>CC</sub> = 6.0 V	17	6	-	21	-	26	-	ns

### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions		25 °C			°C to		°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>su</sub>	set-up time	DS to CP, CE; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	80	11	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	4	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	3	-	17	-	20	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	5	-	17	-	20	-	ns
		Dn to PL; see Fig. 11								
		V <sub>CC</sub> = 2.0 V	80	22	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	8	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns
t <sub>h</sub>	hold time	DS to CP, CE and Dn to PL; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	5	2	-	5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V	5	2	-	5	-	5	-	ns
		V <sub>CC</sub> = 6.0 V	5	2	-	5	-	5	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 2.0 V	5	-17	-	5	-	5	-	ns
		V <sub>CC</sub> = 4.5 V	5	-6	-	5	-	5	-	ns
		V <sub>CC</sub> = 6.0 V	5	-5	-	5	-	5	-	ns
f <sub>max</sub>	maximum	CP input; see Fig. 7								
	frequency	V <sub>CC</sub> = 2.0 V	6	17	-	5	-	4	-	MHz
		V <sub>CC</sub> = 4.5 V	30	51	-	24	-	20	-	MHz
		V <sub>CC</sub> = 6.0 V	35	61	-	28	-	24	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	56	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; $V_I = GND$ to $V_{CC}$ [3]	-	35	-	-	-	-	-	pF
74HCT1	65			l			l			
t <sub>pd</sub>	propagation	CE, CP to Q7, Q7; see Fig. 7 [1]								
·	delay	V <sub>CC</sub> = 4.5 V	-	17	34	-	43	-	51	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	-	-	ns
		PL to Q7, Q7; see Fig. 8								
		V <sub>CC</sub> = 4.5 V	-	20	40	-	50	-	60	ns
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	17	-	-	-	-	-	ns
		D7 to Q7, Q7; see Fig. 9								
		V <sub>CC</sub> = 4.5 V	-	14	28	-	35	-	42	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	_	11	_	_	-	_	_	ns

#### 8-bit parallel-in/serial out shift register

Symbol	Parameter	Conditions	25 °C				°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>t</sub>	transition time	Q7, Q7 output; see Fig. 7 [2]								
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
t <sub>W</sub>	pulse width	CP input; see Fig. 7								
		V <sub>CC</sub> = 4.5 V	16	6	-	20	-	24	-	ns
		PL input; see Fig. 8								
		V <sub>CC</sub> = 4.5 V	20	9	-	25	-	30	-	ns
t <sub>rec</sub>	recovery time	PL to CP, CE; see Fig. 8								
		V <sub>CC</sub> = 4.5 V	20	8	-	25	-	30	-	ns
t <sub>su</sub>	set-up time	DS to CP, CE; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	20	2	-	25	-	30	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	20	7	-	25	-	30	-	ns
		Dn to PL; see Fig. 11								
		V <sub>CC</sub> = 4.5 V	20	10	-	25	-	30	-	ns
t <sub>h</sub>	hold time	DS to CP, CE and Dn to PL; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	7	-1	-	9	-	11	-	ns
		CE to CP and CP to CE; see Fig. 10								
		V <sub>CC</sub> = 4.5 V	0	-7	-	0	-	0	-	ns
f <sub>max</sub>	maximum	CP input; see Fig. 7								
	frequency	V <sub>CC</sub> = 4.5 V	26	44	-	21	-	17	-	MHz
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	48	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	per package; [3] V <sub>I</sub> = GND to V <sub>CC</sub> - 1.5 V	-	35	-	-	-	-	-	pF

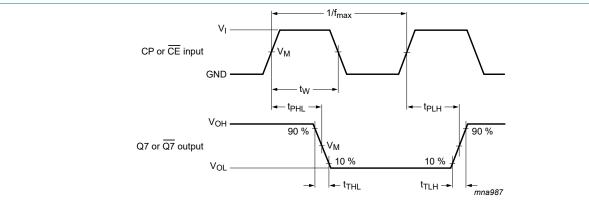
f<sub>o</sub> = output frequency in MHz;

 $\Sigma$  (C<sub>L</sub> × V<sub>CC</sub> <sup>2</sup> × f<sub>o</sub>) = sum of outputs; C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V.

 $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;

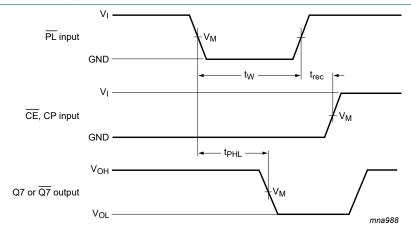
#### 11.1. Waveforms and test circuit



Measurement points are given in Table 8.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

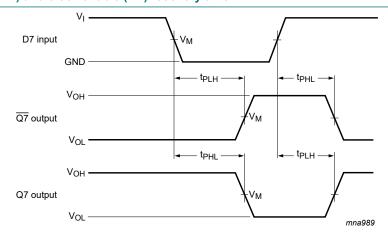
Fig. 7. The clock (CP) or clock enable (CE) to output (Q7 or Q7) propagation delays, the clock pulse width, the maximum clock frequency and the output transition times



Measurement points are given in Table 8.

V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

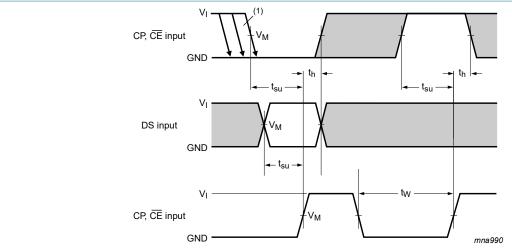
Fig. 8. The parallel load (PL) pulse width, the parallel load to output (Q7 or Q7) propagation delays, the parallel load to clock (CP) and clock enable (CE) recovery time



Measurement points are given in Table 8.

 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

Fig. 9. The data input (D7) to output (Q7 or  $\overline{Q7}$ ) propagation delays when  $\overline{PL}$  is LOW

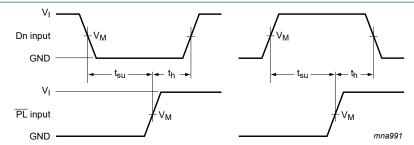


(1)  $\overline{\text{CE}}$  may change only from HIGH-to-LOW while CP is LOW.

The shaded areas indicate when the input is permitted to change for predictable output performance Measurement points are given in <u>Table 8</u>.

 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

Fig. 10. The set-up and hold times from the serial data input (DS) to the clock (CP) and clock enable (CE) inputs, from the clock enable input (CE) to the clock input (CP) and from the clock input (CP) to the clock enable input (CE)



Measurement points are given in Table 8.

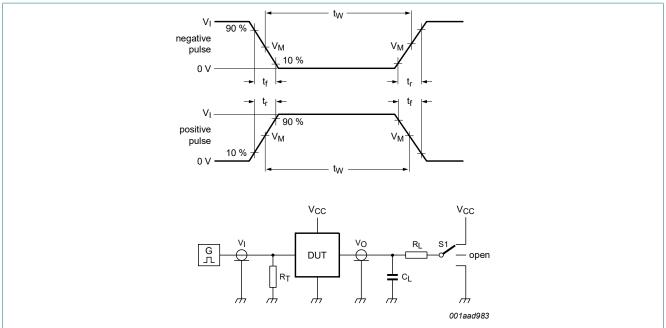
V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig. 11. The set-up and hold times from the data inputs (Dn) to the parallel load input (PL)

**Table 8. Measurement points** 

Туре	Input	Output	
	V <sub>I</sub>	V <sub>M</sub>	V <sub>M</sub>
74HC165	V <sub>CC</sub>	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT165	3 V	1.3 V	1.3 V

#### 8-bit parallel-in/serial out shift register



Test data is given in Table 9.

Definitions for test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_{l}$  = Load resistance.

S1 = Test selection switch

Fig. 12. Test circuit for measuring switching times

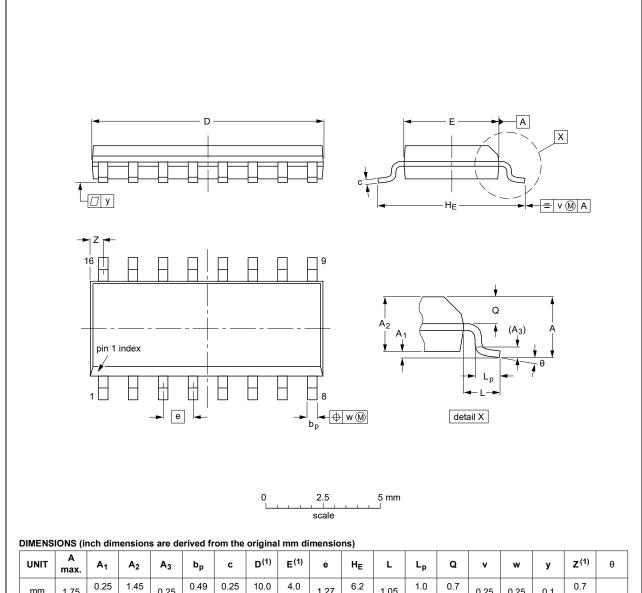
Table 9. Test data

Туре	Input		Load	S1 position	
	V <sub>I</sub>	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>	$R_L$	t <sub>PHL</sub> , t <sub>PLH</sub>
74HC165	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT165	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

### 12. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	<b>A</b> <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.020	0.01	0.01	0.004	0.028 0.012	0°

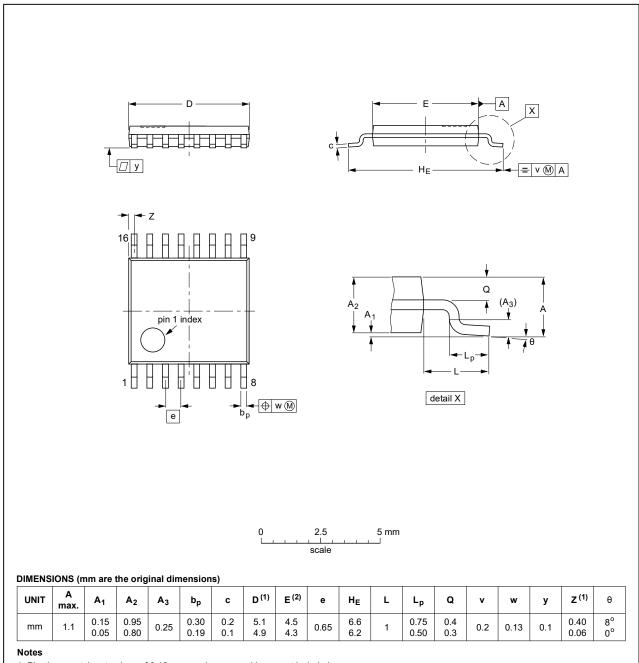
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

Fig. 13. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18

Fig. 14. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

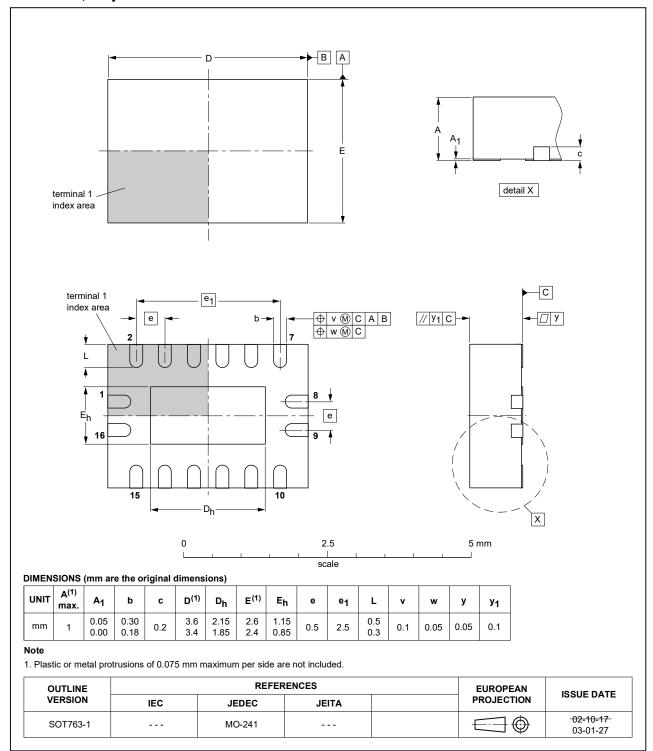


Fig. 15. Package outline SOT763-1 (DHVQFN16)

### 13. Abbreviations

#### **Table 10. Abbreviations**

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

### 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT165 v.7	20210901	Product data sheet	-	74HC_HCT165 v.6			
Modifications:	1	Section 2 updated.  Type numbers 74HC165DB and 74HCT165DB (SOT338-1/SSOP16) removed.					
74HC_HCT165 v.6	20200423	200423 Product data sheet - 74HC_HCT165 v.5					
Modifications:	• Table 4: Der	rating values for P <sub>tot</sub> total p	ower dissipation ι	ıpdated.			
74HC_HCT165 v.5	20170821	Product data sheet	-	74HC_HCT165 v.4			
Modifications:	The format of guidelines of the guidelines	<ul> <li>Table 7: Hold time for 74HC165 has been updated.</li> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
74HC_HCT165 v.4	20151228	Product data sheet	-	74HC_HCT165 v.3			
Modifications:	Type number	ers 74HC165N and 74HCT	165N (SOT38-4)	removed.			
74HC_HCT165 v.3	20080314	Product data sheet	-	74HC_HCT165_CNV v.2			
Modifications:	guidelines o Legal texts Package SC	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Package SOT763-1 (DHVQFN16) added to Section 4 and Section 12.</li> <li>Family data added, see Section 10</li> </ul>					
74HC_HCT165_CNV v.2	December 1990	Product specification	-	-			

#### 8-bit parallel-in/serial out shift register

### 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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#### 8-bit parallel-in/serial out shift register

#### **Contents**

1.	General description	1
2.	Features and benefits	. 1
3.	Applications	. 1
4.	Ordering information	2
5.	Functional diagram	2
6.	Pinning information	3
6.1	. Pinning	3
6.2	. Pin description	3
7.	Functional description	. 4
8.	Limiting values	. 5
9.	Recommended operating conditions	5
10.	Static characteristics	5
11.	Dynamic characteristics	7
11.	Waveforms and test circuit	10
12.	Package outline	13
13.	Abbreviations	16
14.	Revision history	16
	Legal information	

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